Supplementary information for

Phase-engineered cathode for super-stable potassium storage

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Supplementary Figure 1. XRD patterns and the corresponding JCPDS data of VO_2 (a), VO_2 (B), and VO_2 (M).



Supplementary Figure 2. FE-SEM images for the several types of VO₂ on the carbon fiber cloth. Low-magnification FE-SEM images of a), b) VO_2 (a), d) VO_2 (B), and g) VO_2 (M). High-magnification FE-SEM images of c) VO_2 (a), e) VO_2 (B), and h) VO_2 (M). Cross-sectional FE-SEM images of f) VO_2 (B) and i) VO_2 (M).



Supplementary Figure 3. EDS results of VO₂ (a).



Supplementary Figure 4. Morphology and structural characterization of the pristine materials. The HRTEM images at atomic resolution of pristine a) VO_2 (a), d) VO_2 (B), and h) VO_2 (M). Their corresponding FFT patterns are shown in b), e), and i), respectively. Schematic illustrations of c) VO_2 (a), g) VO_2 (B), and k) VO_2 (M). The simulated diffraction patterns of f) VO_2 (B) and j) VO_2 (M).



Supplementary Figure 5. Cycle life performance of $VO_2(a)$ at 200 mA g⁻¹.



Supplementary Figure 6. XRD patterns of VO₂ (a) powder, VO₂ (B) powder, and VO₂ (M) powder.



Supplementary Figure 7. Material characterizations of amorphous VO₂ powders.

a) and b) The FE-SEM images of amorphous VO_2 powder.



Supplementary Figure 8. Material characterization and electrochemical performance of pure CF. a) XRD pattern and b) cycle performance at 50 mA g^{-1} for pure CF.



Supplementary Figure 9. XPS spectra of V 2p of a) VO₂ (a), b) VO₂ (B) and c) VO₂

(M) at pristine state and discharged state of 1 V.



Supplementary Figure 10. In situ XRD patterns of a) VO_2 (a), b) VO_2 (B), and c) VO_2 (M) half cells during a cycle and the corresponding galvanostatic curves. The peak positions marked by the following symbols are due to the Be disk: \blacktriangle : Be₁₁Fe; \bullet : Be₁₂Cr; \blacksquare : Be₂Cr; \bigstar : BeS.



Supplementary Figure 11. In situ XRD test with a blank sample. The peaks labeled with different symbols on the peaks correspond to: \blacktriangle : Be₁₁Fe; \bullet : Be₁₂Cr; \blacksquare : Be₂Cr; \bigstar : BeS.



Supplementary Figure 12. The electrokinetic analyses conducted by CV test. a), e), and i) CV curves for VO₂ (a), VO₂ (B), and VO₂ (M) at different scan rates. b), f) and j) Relationship between the logarithmic scan rates and logarithmic peak currents. c), g) and k) Contribution of pseudocapacitive capacities for K⁺ storage at different scan rates. d), h), and l) The capacitive fractions at a scan rate of 1.0 mV s⁻¹ for VO₂ (a), VO₂ (B), and VO₂ (M), respectively.



Supplementary Figure 13. Investigation of the K⁺ ions migration kinetics by GITT. Transient voltage profiles versus specific capacity for potassiation/de-potassiation in a) $VO_2(a)$, b) $VO_2(B)$, and c) $VO_2(M)$ obtained from GITT. A single step of GITT for d) $VO_2(a)$, e) $VO_2(B)$, and f) $VO_2(M)$ during the initial discharge process.



Supplementary Figure 14. The chemical diffusion coefficient D_K calculated by GITT. The representation transient voltage of a galvanostatic pulse as a function of the square root of time from GITT for a) VO₂ (a), b) VO₂ (B), and c) VO₂ (M). The calculated chemical diffusion coefficient D_K versus voltage for d) VO₂ (a), e) VO₂ (B), and f) VO₂ (M), respectively.



Supplementary Figure 15. The electrochemical impedance spectroscopy. a) An equivalent circuit model for the impedance spectra. Nyquist plots for VO₂ in different phases at b) open-circuit voltage states, c) charged states after 100 cycles, and d) charged states after 1000 cycles.



Supplementary Figure 16. The FE-SEM images after cycling. FE-SEM of a), b) VO₂ (a), c), d) VO₂ (B), and e), f) VO₂ (M) after 100 cycles at charged states.



Supplementary Figure 17. Elemental mappings of V and O for a) VO₂ (a), b) VO₂ (B), and c) VO₂ (M).



Supplementary Figure 18. Strain mapping with uniaxial strain components ε_{xx} (left) and ε_{yy} (right), as obtained by GPA of the HRTEM image for pristine VO₂ (B).



Supplementary Figure 19. Von Mises stress within the a) $VO_2(a)$, b) $VO_2(B)$, and c)

 $VO_2(M)$ particles at different times along the radial direction.



Supplementary Figure 20. 3D view of equivalent stress after K⁺ ions diffusion in a)

 VO_2 (B) particle for 160 ms, and b) VO_2 (M) particle for 400 ms, respectively.



Supplementary Figure 21. The schematic structural changes for VO₂ (a) and VO₂ (B) during the potassiation and depotassiation.



Supplementary Figure 22. Comparison of full battery a) rate capability and b) cycling performance of VO_2 (a) as the cathode with the reported systems¹⁻⁷.



Supplementary Figure 23. The FE-SEM images of VO₂ (a) after bending 1000 times at charged states.

C 76.09 87.92 O 9.37 8.12	Element	Wt %	Atomic %
O 9.37 8.12	С	76.09	87.92
TT	Ο	9.37	8.12
V 14.54 3.96	V	14.54	3.96

Supplementary Table 1. The atomic ratio of elements from EDS.

Sample	Item	Initial	100 cycles	1000 cycles
VO ₂ (a)	$R_e(\Omega)$	6.319	15.74	22.93
	$ m R_{f}(\Omega)$	1.45	127.5	93
	$R_{ct}(\Omega)$	3904	2414	756.7
VO ₂ (B)	$R_e(\Omega)$	6.08	7.123	8.144
	$ m R_{f}(\Omega)$	2.407	754.8	470.4
	$R_{ct}(\Omega)$	5421	3462	2315
VO ₂ (M)	$R_e(\Omega)$	8.008	10.13	9.684
	$ m R_{f}(\Omega)$	1.258	1245	483.8
	$R_{ct}(\Omega)$	8345	4418	2534

Supplementary Table 2. The fitting results of EIS for VO₂ in different phases.

Sample	Volume (cm ³)	Density $(g \text{ cm}^{-3})$	Elapsed Time (mm:ss)	Temperature
				(°C)
1	0.1802	2.8075	11:13	31.14
2	0.1800	2.8100	13:46	31.18
3	0.1797	2.8141	16:15	31.24
4	0.1804	2.8031	18:49	31.29
5	0.1809	2.7961	21:22	31.29

Supplementary Table 3. The density test results for amorphous VO₂ powders.

Supplementary References

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